

Supplementary Material

Structural and chemical peculiarities of nitrogen-doped graphene grown by direct microwave plasma-enhanced chemical vapor deposition

Šarūnas Meškinis ¹, Rimantas Gudaitis ¹, Mindaugas Andrulevičius ¹ and Algirdas Lazauskas ^{1,*}

¹ Institute of Materials Science, Kaunas University of Technology, K. Baršausko 59, LT51423 Kaunas, Lithuania; mindaugas.andrulevicius@ktu.lt (M.A.); rimantas.gudaitis@ktu.lt (R.G); sarunas.meskinis@ktu.lt (Š.M.);

* Correspondence: algirdas.lazauskas@ktu.edu (A.L.); Tel.: +370-671-73375

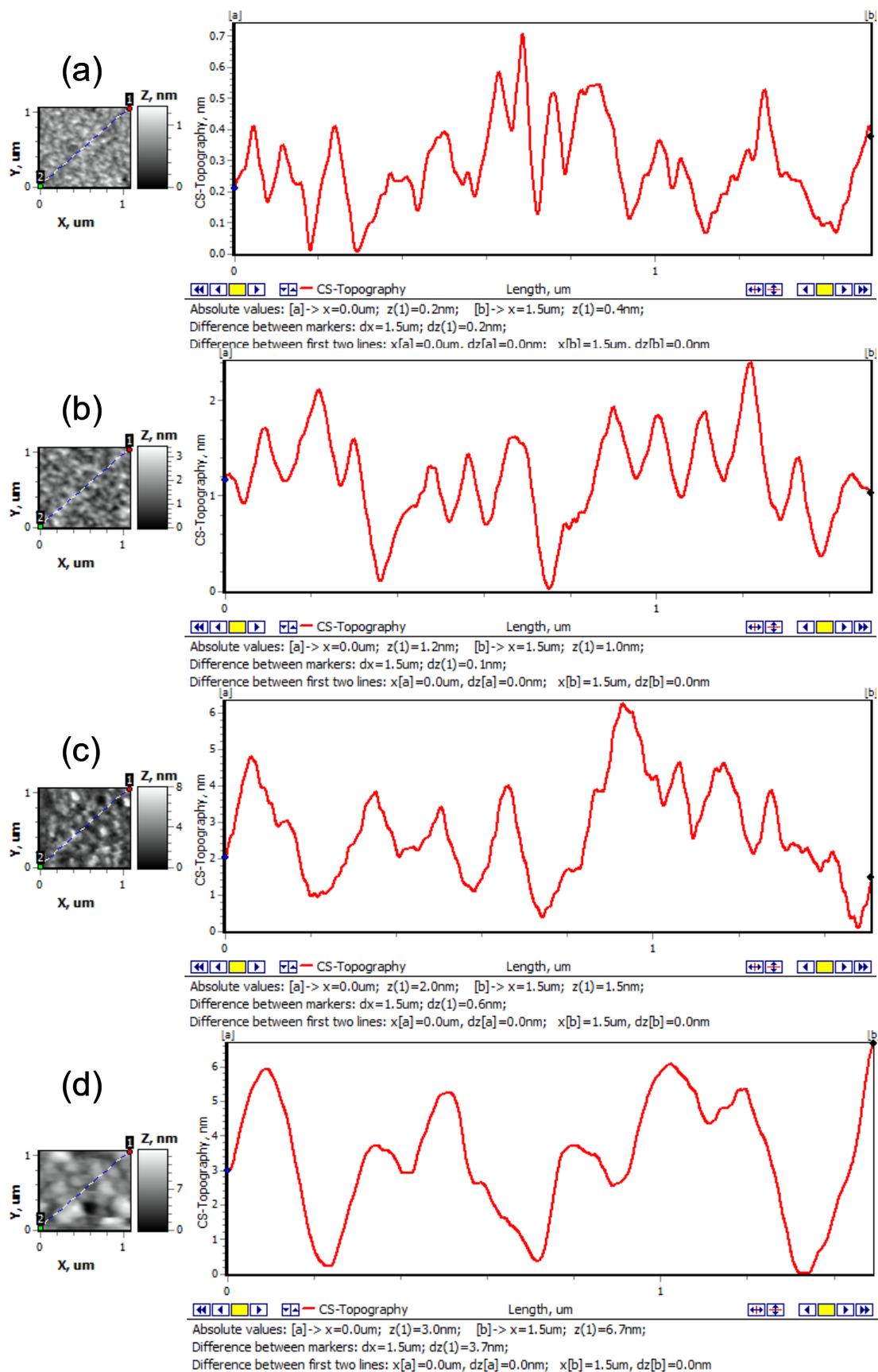


Figure S1. Characteristic height profiles for the corresponding lines drawn in AFM images of pristine graphene (a), N35 (b), N75 (c) and N110 (d)

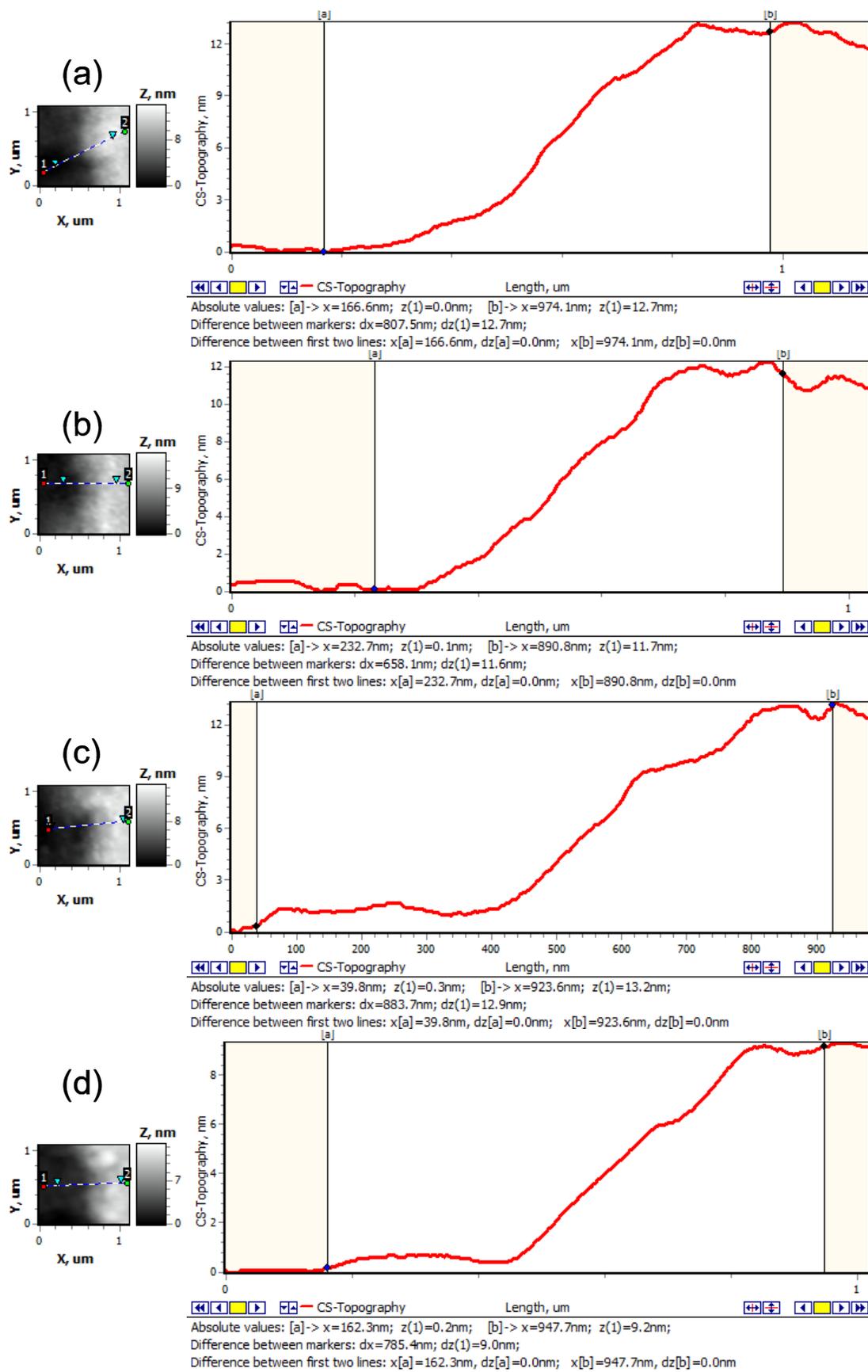


Figure S2. Characteristic step profiles for the corresponding lines drawn in AFM images of pristine graphene (a), N35 (b), N75 (c) and N110 (d)

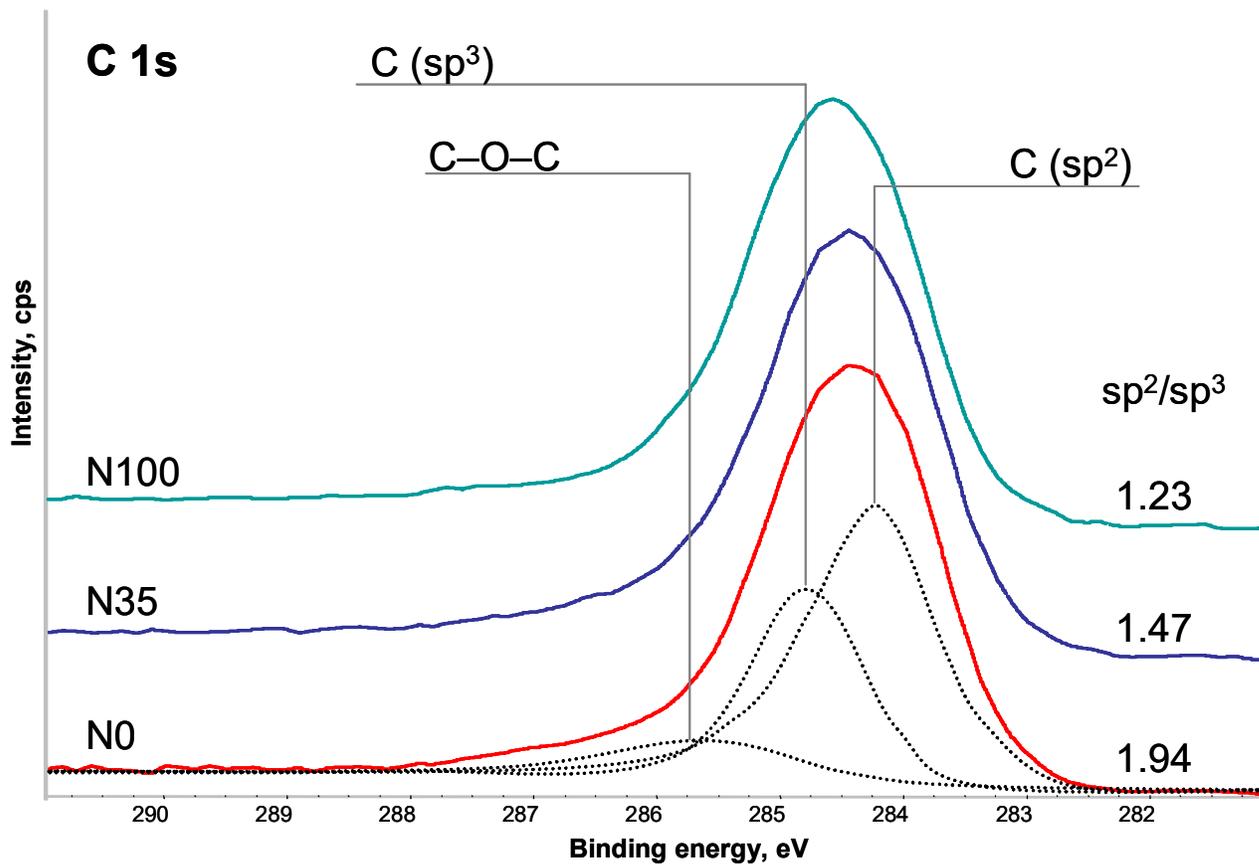


Figure S3. Deconvoluted high resolution XPS spectra in C 1s region of N0, N35 and N110